

Memory Module Specification

KVR800D2S6/4G 4GB 512M x 64-Bit DDR2-800 CL6 200-Pin SODIMM

DESCRIPTION:

This document describes ValueRAM's 512M x 64-bit 4GB (4096MB) CL6 DDR2-800 SDRAM (Synchronous **DRAM**) memory module. The components on this module include sixteen stacked 256M x 8-bit DDR2-800 SDRAM. This 200-pin SODIMM uses gold contact fingers and requires +1.8V. The electrical and mechanical specifications are as follows:

FEATURES:

Clock Cycle Time (tCK) CL=6	2.5ns
Row Cycle Time (tRC)	60ns (min.)
Refresh to Active/Refresh Command Time (tRFC)	195ns
Row Active Time (tRAS)	45 ns (min.) / 70,000 ns (max.)
Single Power Supply of	+1.8V (+/1V)
Power	1.440W (operating)
ULRating	94 V - 0

Note: The module defined in this data sheet is one of several configurations available under this part number. While all configurations are compatible, the DRAM combination and/or the module height may vary from what is described here.

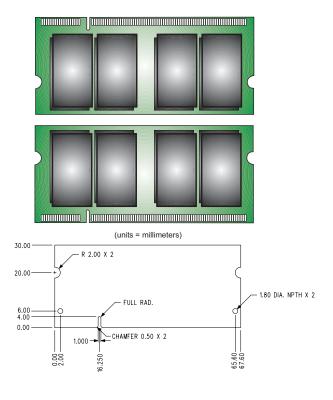


Figure 1: KVR800D2S6/4G 200-Pin SODIMM